

DAFTAR PUSTAKA

- [1] Rashid, Muhammad. 2006. Power Electronics HandBook second edition. ACademic Press. USA.
- [2] Ramdhani, Husni. 2015. Rancang Bangun Dan Analisis Half Bridge Current Source Inverter (CSI) Dengan Kontrol Sinusoidal Pulse Width Modulation (SPWM) Berbasis Mikrokontroler Atmega16. Tugas Akhir. Purwokerto: Universitas Jenderal Soedirman
- [3] Muse, Alif. 2016. Rancang Bangun Dan Analisis Full Bridge Current Source Inverter Dengan Kontrol Modified Sins. Tugas Akhir. Purwokwrto: Universitas Jenderal Soedirman.
- [4] Zainal, Salam. 2003. Power Electronic and Drives (Version 3-2003). Johor Bahru : Universiti Teknologi Malaysia.
- [5] Rashid, Muhammad. 1999. Power Electronics Circuits, Devices, And Applications Third Edition. USA : Pearson Prentice Hall.
- [6] Suroso and Noguchi, Toshihiko. 2010. New H-Bridge Multilevel Current-Source PWM Inverter With Reduced Switching Device Count. International Power Electronic Conference. Japan
- [7] Saputra, M.W. 2014. Rancang Bangun Neutral Point Shorted Inverter 3 Sakelar Kapasitas 1kW Dengan Kontrol Level Shifted Carrier Based Sinusoidal Pulse Width Modulation.
- [8] Amelia, Risti. 2012. Studi Analisi Rugi-rugi Pada Five Level Inverter H-Bridge Current Source Inverter dengan Sinusoidal Pulse Modulation.

- [9] Sunomo, 1999. Power Mosfet dan IGBT, Piranti Elektronika yang Saling Bersaing di Bidang Elektronika Daya. Elektronika Indonesia Nomor 27, Tahun VI, Agustus 1999.
- [10] Siregar ,Dolly Artur. 2013. Rancang Bangun Boost-Up Chopper 24 Volts-320Volts dengan Kendali PI Berbasis Mikrokontroller.Purwokerto: Universitas Jenderal Soedirman.
- [11] Suroso dan Noguchi. 2010. A new three-level current-source PWM inverter and its application for grid connected power conditioner.
- [12] Helly, A., 2012. Inverter Satu Fase Sinkron Berbasis Digital Phase Locked Loop. Tesis. Depok: Universitas Indonesia
- [13] Travis, B. 1996. MOSFETs and IGBTs Differ in Drive Methods and Protection Needs. EDN Asia.
- [14] Ramdhani, M. (2008). Rangkaian Listrik. Bandung: Erlangga
- [15] Wojslawowicz E, J. 1995. Understanding Third-Generation IGBT Switch CharACteristics. Asian Electronics Engineer.